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DESCRIPTION

The A3085A is a half-duplex RS-485 transceiver with ± 15 kV IEC 61000-4-2 contact ESD protection. This device contains one driver and one receiver. The A3085A includes fail-safe circuitry, which guarantees a logic-high receiver output when the receiver inputs are open or shorted. This means that the receiver output will be logic high even if all transmitters on a terminated bus are disabled. The A3085A features reduced slew-rate driver that minimizes EMI and reduces reflections caused by improperly terminated cables, allowing error-free data transmission up to 500kbps. The A3085A has a 1/8 unit load receiver input impedance that allows up to 256 transceivers on the bus.

The A3085A is available in SOP8 package

FEATURES

- +3.3V or +5V Operation
- True Fail-Safe Receiver
- Maximum Data Rate: 500kbps (V_{cc}=5V)
 250kbps (V_{cc}=22)

250kbps (V_{CC}=3.3V)

- Allow Up to 256 Transceivers on the Bus
- I/O Pins ESD Protection: ±15kV IEC 61000-4-2, Contact Discharge
- Available in SOP8 package

APPLICATION

- Smart Meter
- DVR
- RS-485 Communications
- Level Translators
- Transceivers for EMI-Sensitive Applications
- Industrial-Control Local Area Networks
- Energy Meter Networks
- Lighting Systems

ORDERING INFORMATION

Package Type	Part Number			
SOP8	MO	A3085AM8R		
SPQ: 4,000pcs/Reel	M8	A3085AM8VR		
Note	V: Halogen free Package			
Note	R: Tape & Reel			
AiT provides all RoHS products				

TYPICAL APPLICATION



Typical Half-Duplex RS-485 Network



PIN DESCRIPTION



FUNCTION TABLE

Transmitting							I	Receiving	
	Inputs		Out	puts	Inputs O			Outputs	
/RE	DE	DI	А	В		/RE	DE	A-B	RO
х	1	1	1	1 0		0	Х	>-50mV	1
	4	0	0			0	Х	<-200mV	0
X	1	0	0	1		0	Х	Open/Shorted	1
0	0	Х	High-Z	High-Z		1	1	Х	High-Z
1	0	0 X	Shutdown (High-Z)					X	Shutdown
I	0					1	U	X	(High-Z)



ABSOLUTE MAXIMUM RATINGS

Vcc, Power Supply	+7V
/RE, DE, Control Input Voltage	-0.3V ~ V _{CC} +0.3V
DI, Transmitter Input Voltage	$-0.3V \sim V_{CC} + 0.3V$
A, B, Transmitter Output Voltage	±13V
A, B, Receiver Input Voltage	±13V
RO, Receiver Output Voltage	-0.3V ~ V _{CC} +0.3V
Operating Temperature	-40°C ~ +85°C
Storage Temperature	-65°C ~ +150°C
Operating Junction Temperature	125°C

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



DC ELECTRICAL CHARACTERISTICS

(5V Operation)

 V_{CC} =+5V±5%, T_A=-40°C ~ +85°C, Typical Values are V_{CC} =+5V and T_A = 25°C^{NOTE1}

Parameter	Symbol	Conditio	Min.	Тур.	Max.	Unit		
Power Supply	Vcc			4.5	-	5.5	V	
Driver								
Differential Driver Output	N				-		V	
(no load)	VOD1	Figure 1		-		Vcc		
Differential Driver Output	V _{OD2}	Figure 1, R=27Ω		1.5	-	-	V	
Change in Magnitude of		Eiguro 1 P-270			-	0.2	V	
Differential Output Voltage ^{NOTE2}	Δvod			-				
Driver Common-mode Output	Vac	Figure 1 P-270		1.0		2.0	V	
Voltage	VOC			1.0	_	5.0		
Change in Magnitude of		Figure 1 R=270		_	_	0.2	V	
Common-Mode Voltage ^{NOTE2}	Δvoc			-	_	0.2	v	
Input High Voltage	Vih	DE, DI, /RE		2.0	-	-	V	
Input Low Voltage	VIL	DE, DI, /RE		-	-	0.8	V	
DI Input Hysteresis	VHYS		1	-	100	-	mV	
Input Current(A and B)	lin4	DE=GND, Vcc=	V _{IN} =12V	-	-	125	μA	
		GND or 5.25V	V _{IN} =-7V	-75	-	-		
Driver Short-Circuit Output	laas	A Din Short to B Din	100		100	m۸		
Current	IOSD			-100		100		
Receiver								
Receiver Differential Threshold	V	V/	200	-125	-50	mV		
Voltage	VIH	-7VSVCMS12V					-200	
Receiver Input Hysteresis	ΔVτη			-	40	-	mV	
Receiver Output High Voltage	Vон	I _O =-8mA, V _{ID} =-50)mV	4.0	-	-	V	
Receiver Output Low Voltage	Vol	Io=8mA, VID=-20	0mV	-	-	0.4	V	
Three-State Output Current at	lozo					±1		
Receiver	IOZR			-	-	<u>т</u> і	μA	
Receiver Input Resistance	RIN	-7V≤V _{CM} ≤12V		96	-	-	kΩ	
Receiver Output	loop	0\/<\/po<\/oo		+7		+05	m۸	
Short-Circuit Current	IOSR			11	-	193	ША	
Supply Current	Supply Current							
Supply Current	laa	No load, /RE=	DE=Vcc	-	350	600	μA	
	ICC	DI=GND or V _{CC}	DE=GND	-	370	600	μA	
Supply Current in Shutdown	loursu	DE=GND, /RE=\	/cc,			10		
Mode	ISHDN	DI=V _{CC} or GND		-	-	10	μΑ	



(3.3V Operation)

 V_{CC} =+3.3V±5%, T_A =-40°C ~ +85°C, Typical Values are V_{CC} =+3.3V and T_A = 25°C^{NOTE1}

Parameter	Symbol	Conditio	Min.	Тур.	Max.	Unit	
Power Supply	Vcc			3	-	3.6	V
Driver				-	-		
Differential Driver Output (no load)	V _{OD1}	Figure 1		-	-	Vcc	V
Differential Driver Output	V _{OD2}	Figure 1, R=27Ω		0.8	1.15	-	V
Change in Magnitude of Differential Output Voltage ^{NOTE2}	ΔV_{OD}	Figure 1, R=27Ω		-	-	0.2	V
Driver Common-mode Output Voltage	V _{oc}	Figure 1, R=27Ω		1.0	-	3.0	V
Change in Magnitude of Common-Mode Voltage ^{NOTE2}	ΔVoc	Figure 1, R=27Ω		-	-	0.2	V
Input High Voltage	VIH	DE,DI,/RE		2.0	-	-	V
Input Low Voltage	VIL	DE,DI,/RE		-	-	0.8	V
DI Input Hysteresis	VHYS			-	100	-	mV
Input Current(A and B)	I _{IN4}	DE=GND, Vcc= GND or 3.6V	V _{IN} =12V V _{IN} =-7V	- -75-	-	125 -	μA
Driver Short-Circuit Output Current	I _{OSD}	A Pin Short to B Pin		-100	-	100	mA
Receiver							
Receiver Differential Threshold Voltage	Vтн	-7V≦V _{CM} ≦12V		-200	-125	-50	mV
Receiver Input Hysteresis	ΔVτη			-	40	-	mV
Receiver Output High Voltage	V _{OH}	I ₀ =-1.5mA, V _{ID} =-	50mV	4.0	-	-	V
Receiver Output Low Voltage	Vol	Io=2.5mA, VID=-2	200mV	-	-	0.4	V
Three-State Output Current at Receiver	lozr			-	-	±1	μA
Receiver Input Resistance	R _{IN}	-7V≦V _{CM} ≦12V		96	-	-	kΩ
Receiver Output		01/51/ 51/		17		105	
Short-Circuit Current	IOSR	UV≧VRO≧VCC		±7	-	±95	mA
Supply Current							
Supply Current	Icc	No load , /RE= DI=GND or Vcc	DE=V _{cc} DE=GND	-	270 290	600 600	μΑ μΑ
Supply Current in Shutdown Mode	Ishdn	DE=GND, /RE=V _{cc} , DI=V _{cc} or GND		-	-	10	μA

NOTE1: All currents into the device are positive. All currents out of the device are negative. All voltages are referred to device ground unless otherwise noted.

NOTE2: ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when the DI input changes state.



SWITCHING CHARACTERISTICS

(5V Operation)

 V_{CC} =+5V±5%, T_A=-40°C ~ +85°C, Typical values @ V_{CC}=+5V, T_A = 25°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
	t _{DPLH}	Figure 3 and 5, R_{DIFF} =54 Ω	-	300	800	
Driver input to Output	t DPHL	C _{L1} =C _{L2} =100pF	-	300	800	ns
Driver Output Skew	4	Figure 3 and 5, R_{DIFF} =54 Ω			400	ns
T _{dplh} – T _{dphl}	IDSKEW	C _{L1} =C _{L2} =100pF	-	-	100	
		Figure 3 and 5, R_{DIFF} =54 Ω		400	900	ns
Driver Rise or Fail Time	IDR, IDF	C _{L1} =C _{L2} =100pF	-	420		
Maximum Data Rate	Fмах		500	-	-	kbps
		Figure 4 and 6,			000	
Driver Enable to Output High	t dzh	C∟=100pF S2 Closed	-	-	300	ns
		Figure 4 and 6,			500	ns
Driver Enable to Output Low	t dzl	CL=100pF S1 Closed	-	-		
		Figure 4 and 6,			900	ns
Driver Disable Time from Low	I DLZ	C∟=15pF S1 Closed	-	-		
		Figure 4 and 6,		-	800	
Driver Disable Time from High	t dhz	C∟=15pF S2 Closed	-			ns
	trplh	Figure 7 and 9, $ V_{ID} \ge 2.0V$;		150	300	
Receiver Input to Output	tRPHL	rise and fall time of V₀⊵≦15ns	-			ns
TRPLH – TRPHL Differential		Figure 7 and 9, $ V_{ID} \ge 2.0V$;		10	-	ns
Receiver Skew	I RSKD	rise and fall time of Vı⊵≦15ns	-			
Receiver Enable to		Figure 2 and 8,		20	50	ns
Output Low	I RZL	C _{RL} =15pF S1 Closed	-			
Receiver Enable to		Figure 2 and 8,		20	50	ns
Output High	I RZH	C _{RL} =15pF S2 Closed	-			
Receiver Disable Time	4	Figure 2 and 8,		20	60	ns
from Low	I RLZ	C _{RL} =15pF S1 Closed	-	30	60	
Receiver Disable Time		Figure 2 and 8,				ns
from High	I RHZ	C _{RL} =15pF S2 Closed	-	30	60	
Time to Shutdown	t shdn		-	500	1000	ns
Driver Enable from		Figure 4 and6,			0500	
Shutdown to Output High	IDZH(SHDN)	C∟=100pF S2 Closed	-	-	2500	ns
Driver Enable from		Figure 4 and 6,			0500	ns
Shutdown to Output Low	IDZL(SHDN)	C∟=100pF S1 Closed	-	-	2500	
Receiver Enable from	1	Figure 2 and 8,			2500	ns
Shutdown to Output High	(RZH(SHDN)	C _{RL} =15pF S2 Closed	-	-		
Receiver Enable from	1	Figure 2 and 8,			0500	
Shutdown to Output Low	(RZL(SHDN)	C _{RL} =15pF S1 Closed	-	-	2000	ris.



(3.3V Operation)

 V_{CC} =+3.3V±5%, T_A=-40°C ~ +85°C, Typical values are at V_{CC} =+3.3V, T_A = 25°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
	t _{DPLH}	Figure 3 and 5, R_{DIFF} =54 Ω	-	280	800	
Driver input to Output	t DPHL	C _{L1} =C _{L2} =100pF	-	280	800	ns
Driver Output Skew	4	Figure 3 and 5, R_{DIFF} =54 Ω			100	ns
Tdplh – Tdphl	IDSKEW	C _{L1} =C _{L2} =100pF	-	-		
Driver Pice or Fall Time	too too	Figure 3 and 5, R_{DIFF} =54 Ω		450	000	ns
	UR, UF	C _{L1} =C _{L2} =100pF	_	430	300	
Maximum Data Rate	Fmax		250	-	-	kbps
Driver Enable to Output High	t _{DZH}	Figure 4 and 6,	_	_	300	ns
	-92.11	C _L =100pF S2 Closed				_
Driver Enable to Output Low	t _{DZL}	Figure 4 and 6,	-	-	500	ns
· · · · · · · · · · · · · · · · · · ·		C∟=100pF S1 Closed				
Driver Disable Time from Low	t _{DLZ}	Figure 4 and 6,	-	-	900	ns
		C∟=15pF S1 Closed				
Driver Disable Time from High	tонz	Figure 4 and 6,	_	-	800	ns
	-DTIE	C _L =15pF S2 Closed				
Receiver Input to Output	t RPLH	Figure 7 and 9, $ V_{ID} \ge 2.0V$;	_	150	300	ns
	t RPHL	rise and fall time of Vı⊵≦15ns				
Т _{RPLH} – Т _{RPHL} Differential	tesko	Figure 7 and 9, $ V_{ID} \ge 2.0V$;		10	_	ns
Receiver Skew	LINGKD	rise and fall time of Vı⊵≦15ns		10		110
Receiver Enable to	+	Figure 2 and 8,	_	20	50	ns
Output Low	I RZL	C _{RL} =15pF S1 Closed	_			
Receiver Enable to	toru	Figure 2 and 8,		20	50	ns
Output High	IRZH	C _{RL} =15pF S2 Closed	-	20	50	
Receiver Disable Time	+	Figure 2 and 8,		20	60	ns
from Low	IRLZ	C _{RL} =15pF S1 Closed	-	30	00	
Receiver Disable Time	1 I	Figure 2 and 8,		20	60	ns
from High	I RHZ	C _{RL} =15pF S2 Closed	-	30		
Time to Shutdown	t shdn		-	500	1000	ns
Driver Enable from	1	Figure 4 and6,			0500	
Shutdown to Output High	(DZH(SHDN)	C∟=100pF S2 Closed	-	-	2500	ns
Driver Enable from		Figure 4 and 6,			0500	ns
Shutdown to Output Low	IDZL(SHDN)	C∟=100pF S1 Closed	-	-	2500	
Receiver Enable from		Figure 2 and 8,			2500	ns
Shutdown to Output High	(RZH(SHDN)	C _{RL} =15pF S2 Closed	-	-		
Receiver Enable from	1	Figure 2 and 8,			0500	
Shutdown to Output Low	[RZL(SHDN)	C _{RL} =15pF S1 Closed	-	-	2500	ns



TEST CIRCUITS AND TIMING DIAGRAMS

Figure 1 : Driver DC Test Load







Figure 5 : Driver Propagation Delays



Figure 2 : Receiver Enable/Disable Timing Test Load













Figure 7 : Receiver Propagation Delays



Figure 8 : Receiver Enable and Disable Times



Figure 9 : Receiver Propagation Delay Test Circuit



BLOCK DIAGRAM





PACKAGE INFORMATION

Dimension in SOP8 (Unit: mm)





BASE METAL	b b1 c1 c
	WITH PLATING SECTION B-B

Symbol	Min	Max		
А	-	1.77		
A1	0.08	0.28		
A2	1.20	1.60		
A3	0.55	0.75		
b	0.39	0.48		
b1	0.38	0.44		
С	0.20	0.26		
c1	0.19	0.21		
D	4.70	5.10		
E	5.80	6.20		
E1	3.70	4.10		
е	1.27	BSC		
h	0.25	0.50		
L	0.50	0.80		
L1	1.05 REF			
θ	0°	8°		



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